

Field induced Lifshitz transition in UPt_2Si_2 : Fermi surface under extreme conditions

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We have measured Hall effect, magnetotransport and magnetostriction on the field induced phases of single crystalline UPt_2Si_2 in magnetic fields up to 60 T at temperatures down to 50 mK. For the magnetic field applied along the c axis we observe strong changes in the Hall effect at the phase boundaries. From a comparison to band structure calculations utilizing the concept of a dual nature of the uranium $5f$ electrons, we find evidence for field induced topological changes of the Fermi surface due to at least one Lifshitz transition. Furthermore, we find a unique history dependence of the magnetotransport and magnetostriction data, indicating that the Lifshitz type transition is of a discontinuous nature, as predicted for interacting electron systems.

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Lifshitz transitions - that is, quantum phase transitions involving topological changes of the Fermi surface, and thus referred to as electronic topological transitions (ETT) - have been proposed to play a major role for the physics of correlated electron systems. Here, a variety of exotic field-induced phases, as well as unconventional pressure induced phases (including unconventional superconducting ones) have been observed and attributed to Lifshitz transitions¹⁻¹¹.

The theory of ETT was developed to account for the ground state properties of certain materials under wide variation of external parameters such as pressure^{12,13}. It considered non-interacting electrons at zero temperature, yielding a continuous transition of $2\frac{1}{2}$ order. Later, based on experimental observations, the case of interacting electrons was treated in detail¹⁴⁻¹⁸. Here, conceptually, a new (low) energy scale is associated with the interacting electron system, which may produce ETT in experimentally accessible magnetic field and pressure ranges of a few 10 T and GPa. As well, it was predicted that for interacting electrons the transitions inherently become discontinuous^{14,15}.

Regarding the experimental verification of ETT, cases of real materials exhibiting Lifshitz transitions are rare. On general grounds, it has been demonstrated that ETT anomalies should be observable in various transport properties^{13,19}. Yet, ETT exist only for zero temperature, and smear out with finite temperature. It is a formidable experimental task to identify a Lifshitz type transition, requiring experiments down to very low temperatures under extreme conditions. As well, for correlated electron systems, calculating the band structure as function of external control parameters is challenging.

In this context, based on the observation in the tetragonal uranium intermetallic UPt_2Si_2 of field induced phases in the range $B \parallel c$ axis ~ 30 T, we have argued

that these are related to Lifshitz type transitions²⁰. In order to test the validity of this concept in UPt_2Si_2 , studies at lowest temperatures and using experimental tools directly testing the Fermi surface (FS) and the order of the phase transitions are required. Combining this with band structure calculations allows an assessment of the nature of the field induced phases in UPt_2Si_2 .

Therefore, we present a study on UPt_2Si_2 under extreme conditions, that is at temperatures down to 50 mK and in fields up to 60 T, using Hall effect, magnetotransport and magnetostriction. Our experiments clearly demonstrate qualitative changes of the FS in high magnetic fields. Our study is complemented by band structure calculations utilizing the concept of a dual nature of the uranium $5f$ electrons, which simulate the effect of magnetic fields on the topology of the band structure. Resulting from these calculations, it is verified that Lifshitz type transitions are induced in UPt_2Si_2 in high magnetic fields.

In zero magnetic field, UPt_2Si_2 undergoes an antiferromagnetic (AFM) transition at $T_N = 32$ K, with magnetic moments $\mu_{ord} \sim 2.5\mu_B$ ferromagnetically aligned within the ab plane, and antiferromagnetically coupled and pointing along the c axis^{21,22}. For magnetic fields $B \parallel a$ axis, aside from the suppression of AFM order, there is a hysteretic high field (~ 40 T) regime, whose nature is not understood as yet^{20,23,24} (Fig. 1). Even more exotically, for fields $B \parallel c$ axis, a complex series of field induced phases is observed above 24 T. Based on the magnetization, it was demonstrated that these phases cannot be attributed only to spin reorientation processes and/or crystal field effects^{20,23,25,26}. Instead, these phases are proposed to reflect Lifshitz type transitions²⁰.

The experiments presented here were performed on single crystalline UPt_2Si_2 , the samples being as-cast, bar shaped with a cross section $\sim 1 \times 1$ mm² and length of a

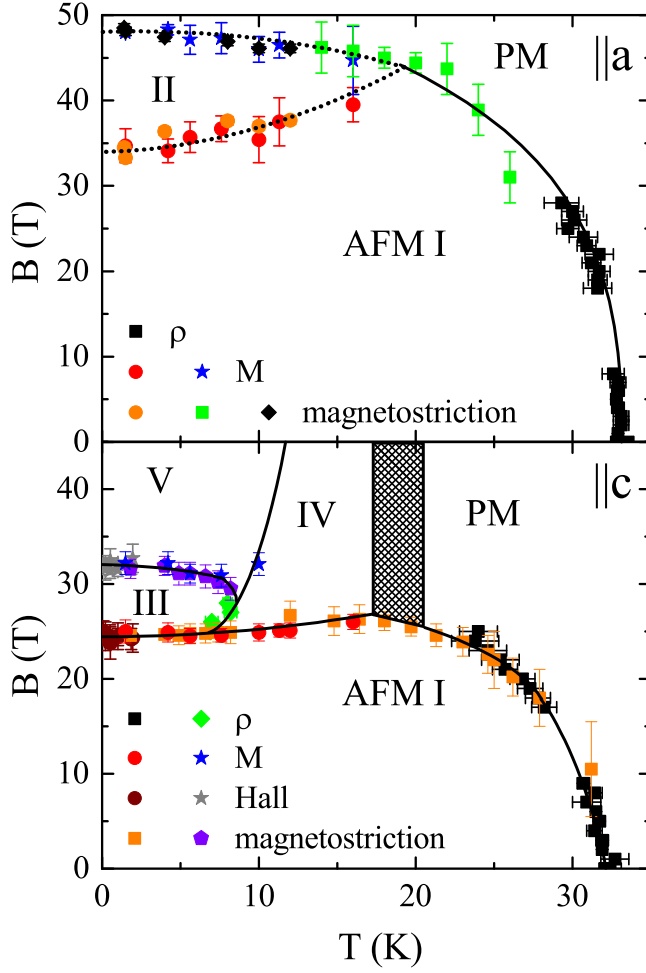


FIG. 1. (Color online) The magnetic phase diagrams of UPt_2Si_2 for the field $B \parallel a$ and c axes from combining the present data with those from in Ref.²⁰; for details see text²⁴.

few mm. Material from the same single crystal has been characterized in the Refs.^{20,22,23,27}.

The electronic transport studies were carried out in the Laboratoire National des Champs Magnétiques Intenses in dc fields up to 34 T directed along a and c axes. For the experiments inside the magnet bore a dilution cryostat was installed. Data were taken with a standard lock-in setup, with a reasonable signal-to-noise ratio obtained with a measurement current of 1 mA directed along the a axis. It resulted in an equilibrium temperature of 120 mK, with additional experiments with lower currents carried out down to 50 mK. Altogether, this way, we have access to a wide range of the field/temperature plane up to a B/T ratio of almost 700 T/K.

The sample was fitted onto a rotatable sample holder and immersed into the helium mixture. Up to 10 electrical contacts were glued on the sample surfaces with silver paint to allow for simultaneous measurements of transverse magnetoresistivity and Hall effect for each magnetic field direction. Axial magnetostriction experiments

were performed at the Los Alamos High Field Laboratory in pulsed fields up to 60 T directed along a and c axes. The base temperature was 1.4 K, with the experiment performed using an optical fiber with a Bragg grating^{28,29}.

For fields $B \parallel a$ axis up to 34 T and low T , the Hall resistivity ρ_{xy} is linear in B (Fig. 2(a)). Consistent with Ref.²⁰, there are no phase transitions in this field range. Next, Hall effect data for $B \parallel c$ axis are included in Fig. 2(a). For fields up to 23 T, *viz.*, in the AFM phase I, ρ_{xy} increases linearly with field^{20,24}. At the phase boundary $I - III$ there is a distinct upward curvature in $\rho_{xy}(B)$, which becomes linear in field again in phase III. At the phase $III - V$ boundary there is a - now downwards - curvature in ρ_{xy} . Within experimental resolution, no hysteresis is observed between field-sweep-up and -down measurements. Qualitatively, this behavior is reminiscent to that of Rh-doped URu_2Si_2 ³⁰.

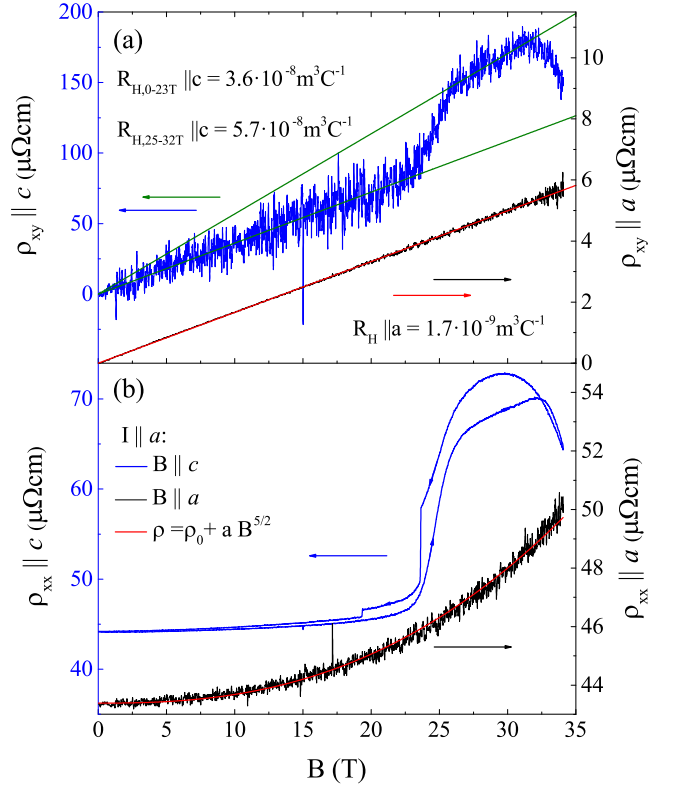


FIG. 2. (Color online) a.) Hall resistivity ρ_{xy} at $T = 300$ mK for $B \parallel a$ and 130 mK for $B \parallel c$ axis, together with fits to the data. b.) Magnetoresistivity of UPt_2Si_2 at $T = 300$ mK for $B \parallel a$ and 120 mK for $B \parallel c$; for details see text.

For parameterization, the Hall effect is fitted using the expression $\rho_{xy} = R_H B$. For $B \parallel a$ axis the data in phase I yield a Hall coefficient $R_H = 1.7 \times 10^{-9} \text{ m}^3/\text{C}$ (solid line in Fig. 2(a)). Correspondingly, for $B \parallel c$ axis the linear regimes from 0 to 23 T and 25 to 32 T lead to Hall coefficients $R_H = 3.6 \times 10^{-8} \text{ m}^3/\text{C}$ and $R_H = 5.7 \times 10^{-8} \text{ m}^3/\text{C}$, respectively. Overall, these values are broadly consistent with the typical behavior of heavy fermion intermetallics.

In magnetic materials, the Hall effect contains two terms. The *normal* contribution $\rho_{xy}^{nor} = R_N B$ measures the carrier density n in units of the electron charge e : $R_N = (ne)^{-1}$. The *anomalous* Hall contribution ρ_{xy}^{ano} reflects terms dependent on scattering and/or magnetization (reported in the Refs.^{20,23,26}). Adding to the data in Ref.²⁰, low temperature magnetoresistivity has been carried out (Fig. 2(b)). At lowest T for $B \parallel a$ axis up to 34 T, for the magnetoresistivity we find to good approximation $\rho_{xx}(B) = \rho_{xx}(B=0) + aB^{\frac{5}{2}}$. In accordance with the Hall effect and Ref.²⁰, we find no evidence for phase transitions.

In contrast, for $B \parallel c$ axis the transitions from phase *I* into *III* and *III* into *V* are reflected by distinct anomalies in the magnetoresistivity. The transition $I \rightarrow III$ is accompanied by a steep increase of the magnetoresistivity, with the midpoint of the upturn close to the transition field determined from magnetization. Conversely, the transition $III \rightarrow V$ shows up as a corresponding drop of the magnetoresistivity.

Surprisingly, the magnetoresistivity $B \parallel c$ axis is accompanied by a curious type of hysteresis: Measurements of $\rho_{xx}(B)$ by sweeping from zero field into phase *V* and back produce hysteresis in the magnetoresistivity (Fig. 2(b)). In contrast, sweeps from zero field only into phase *III* and back produce no hysteresis in $\rho_{xx}(B)$ at low T ²⁴. This suggests that the phase transition $III - V$ is first order.

In terms of the anomalous Hall contribution ρ_{xy}^{ano} , the absence of hysteresis in the Hall effect and its presence in the magnetoresistivity implies that ρ_{xy}^{ano} is not dependent on $\rho_{xx}(B)$. Then, the upturn in ρ_{xy} at the phase $I - III$ boundary might be attributed to the corresponding upturn in the magnetization M (see Refs.^{20,23,26}). Conversely, at the phase $III - V$ boundary the downturn in ρ_{xy} is clearly at odds with the upturn in M . It implies that this phase transition is accompanied by a carrier density change, *i.e.*, it involves a qualitative change of the Fermi surface as in an ETT.

To complement our study on UPt_2Si_2 with a structural probe, we have carried out axial magnetostriction experiments (Fig. 3). For $B \parallel a$ axis we find a contraction of the sample for all fields. Further, a slight change of slope occurs at elevated fields, becoming hysteretic in the temperature/field range, where magnetization hysteresis is observed. The features denote the transition from phase *I* into the paramagnetic state.

For $B \parallel c$ axis the crystal UPt_2Si_2 expands for fields up to ~ 40 T, and at highest fields the magnetostriction saturates. The field-induced phase transitions are identified as additional structure in the magnetostriction. The critical fields of the different phases are identified as points of maximum slope in the field-sweep-up measurements.

Similar to the magnetoresistivity, we find a history dependent hysteresis at low T : For measurements from zero field up into phase *III* and back no hysteresis is observed (inset Fig. 3). Conversely, when the final field lies within phase *V*, structural hysteresis appears. Thus, the struc-

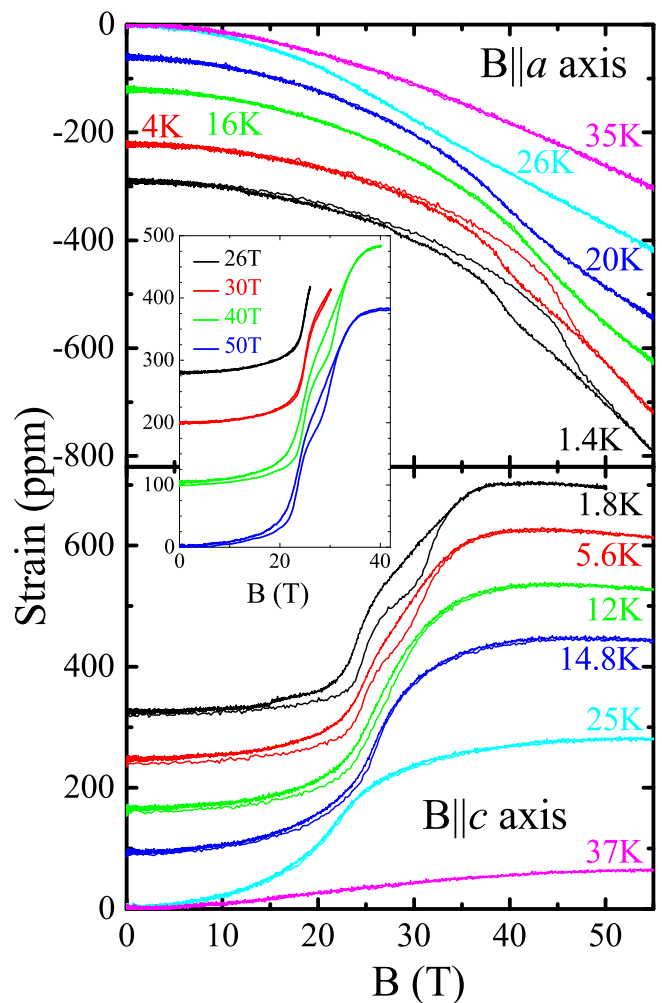


FIG. 3. (Color online) Axial magnetostriction of UPt_2Si_2 for magnetic fields $B \parallel a$ and c axes plotted up to 55 T for various temperatures; data shifted for clarity. The inset illustrates the absence/appearance of structural hysteresis upon ramping the field into phase *III/V* at a temperature of 1.8 K, respectively. The legend in the inset denotes the highest magnetic fields attained for the different magnet runs; for details see text.

tural probe magnetostriction verifies that the phase transition $III - V$ is of a first order nature.

With the present data set we complete our high field studies on UPt_2Si_2 . By combining the new data with those from Ref.²⁰, we present the magnetic phase diagrams of UPt_2Si_2 for $B \parallel a$ and c axes in Fig. 1. The data confirm the existence of an unusual hysteretic regime in UPt_2Si_2 for $B \parallel a$ axis²⁴. Moreover, for $B \parallel c$ axis the experimental evidence is fully consistent with the transition into phase *V* to be an ETT in a correlated electron system. We have observed a significant change of the Hall coefficient at the phase $III - V$ transition for $B \parallel c$ axis, in line with a Lifshitz type character. As well, the first order nature of this transition is consistent with a Lifshitz type transition for an interacting electron system. The relevance of correlation effects in UPt_2Si_2 has recently

been demonstrated in band structure calculations^{31,32}. Therefore, to complement our experimental study, we have carried out additional band structure calculations.

For an ETT, the topological changes in the iso-energy surfaces result from critical points in the band dispersion, *i.e.*, minima, saddle points, and maxima which give rise to van Hove singularities in the density of states. The changes in the topology of the iso-energy surfaces include the appearance or disappearance of small pockets, the formation of voids and the disruption of necks. Therefore, the focus of the present calculations is on critical points in the quasiparticle dispersion of UPt_2Si_2 . For magnetic field-induced Lifshitz transitions, the critical points have to be rather close to the Fermi energy. All in all, it is thus the occurrence of these pockets, voids or necks that we are searching for in the band structure.

The present calculations assume that there are itinerant $5f$ electrons which form partially filled coherent bands. We analyse the FS where the energy bands are calculated under the following assumptions about the nature of the $5f$ electrons: We begin by adopting DFT treating all $5f$ electrons as band states. This approximation scheme cannot fully capture the correlation effects. To simulate the latter we calculate the band structure under the assumption that two of the $5f$ electrons are localized while one may be itinerant and hybridize with the conduction states. For simplicity, we first treat all $5f$ channels as equivalent and account for orbital selection in a second step.

The FS obtained by the three approaches are summarized in the Supplement²⁴. We find four bands crossing the Fermi energy, and denote the corresponding FS sheets as 1, 2, 3 and 4. Globally, the LDA result agrees well with the one obtained by Elgazzar et al.³¹ apart from the fact that the "appendices" are absent in our sheet 1 (see Elgazzar band labelled 113).

With respect to the FS topology, we find that the FS sheets 3 and 4 are remarkably insensitive to the treatment of the $5f$ states. The number of itinerant $5f$ electrons affects only the sheets 1 and 2. Correspondingly, we have inspected closely the response of these sheets on magnetic field by analyzing the iso-energy surfaces for shifts away from the Fermi energy by 6 meV. For a magnetic moment $\sim 2.5 \mu_B$ as in UPt_2Si_2 this value corresponds to a magnetic field of ~ 30 T.

In particular, for sheet 2 we find a qualitative change of the shape of the FS for such a small energy shift, thus providing direct band structure evidence for an ETT (see

Fig. 4). Clearly, a void formation/neck disruption is visible as the iso-energy surface is tuned from -6 meV to +6 meV around the Fermi energy. For FS sheet 1 in the energy range considered we find no topological change.

In summary, we provide experimental evidence for a field-induced first-order Lifshitz type transition in the correlated electron system UPt_2Si_2 through a combined study of the electronic and structural properties. Further, for the FS, critical points close to the Fermi energy E_F are found in the band dispersion when two of the $5f$ electrons are treated as localized, implying that field-induced Lifshitz transitions are to be expected. In contrast, for the all-itinerant model, the critical points leading to Lifshitz transitions are too far from the Fermi energy as to be relevant in an experimental context. Thus, with our study we verify experimentally the predictions made based on the dual model of $5f$ electrons for the case of an uranium intermetallic with strong electronic correlations.

Finally, the question arises about the nature of the other magnetic phases in UPt_2Si_2 for $B \parallel c$ axis. When associating the first-order transition into phase *V* with an ETT, in reverse the second-order character of the phase *I* – *III* transition would signal a more ordinary type of transition as for instance a spin-flop. In turn, it raises questions about the character of phase *IV*. While thermal smearing might prohibit a definite identification, conceptually, phase *IV* can have the FS topology of phase *I/III*, *V* or a different one. Taking this into a more general context, the interplay of spin reorientation/anisotropy and FS topology may give rise to a complex set of field-induced phases in UPt_2Si_2 , and which might bear relevance to related exotic phenomena such as the complex phase diagram of URu_2Si_2 ^{30,33,34}.

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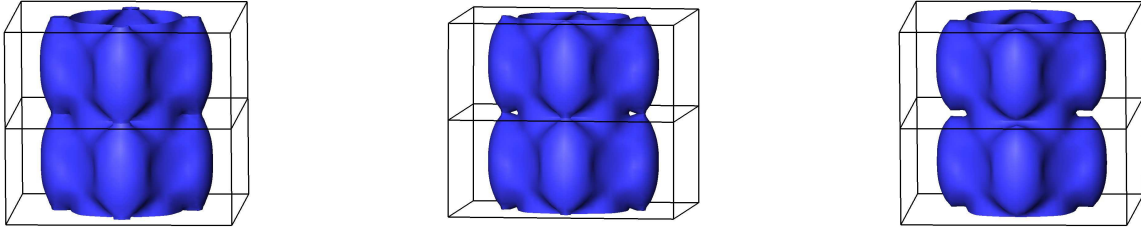


FIG. 4. Lifshitz transitions for the case of two $5f$ electrons treated as localized. The iso-energy surfaces $E = E_F - 6$ meV (left panel), $E = E_F$ (middle) and $E = E_F + 6$ meV (right) show a cascade of ETT by void formation and neck disruption, and which are accessible by magnetic fields in the range of a few 10 T.

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